

# **Device Modeling Report**

**COMPONENTS:**  
DIODE/ SCHOTTKY RECTIFIER / STANDARD  
PART NUMBER: 1SS402  
MANUFACTURER: TOSHIBA

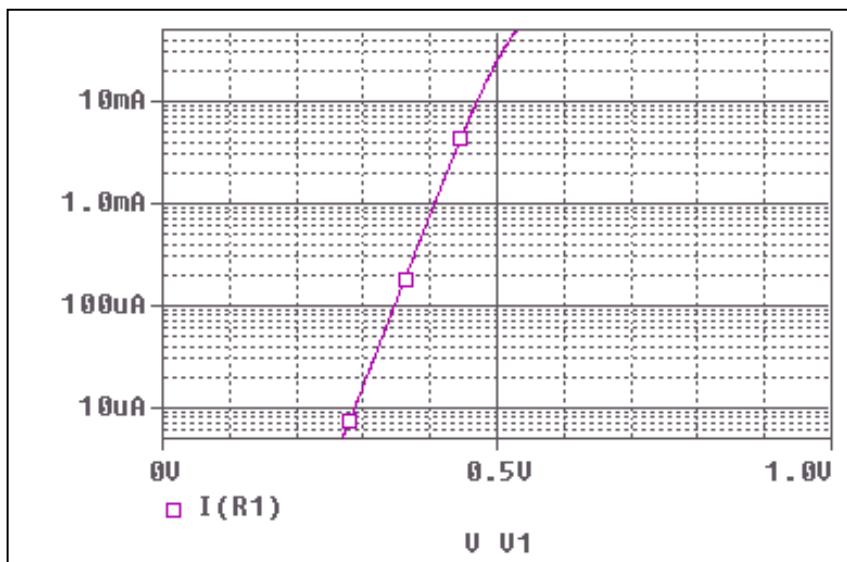


**Bee Technologies Inc.**

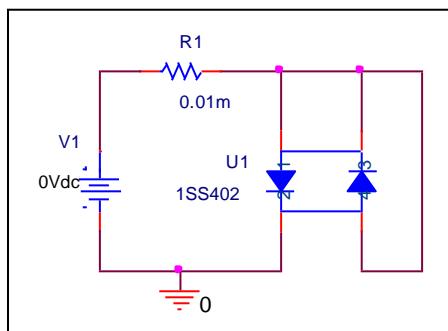
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

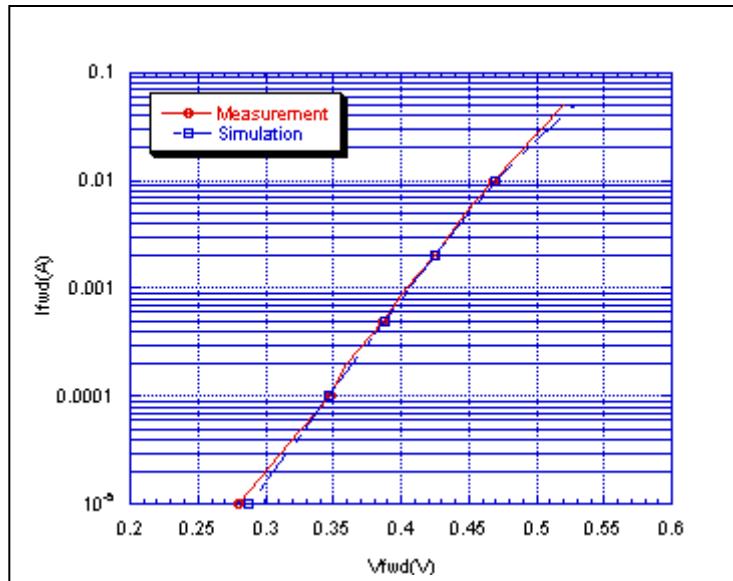


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

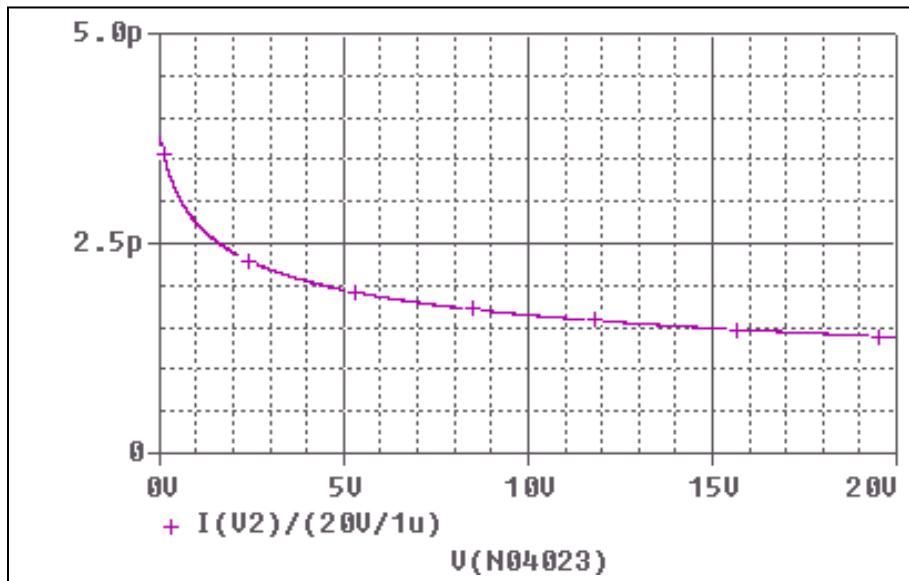


Simulation Result

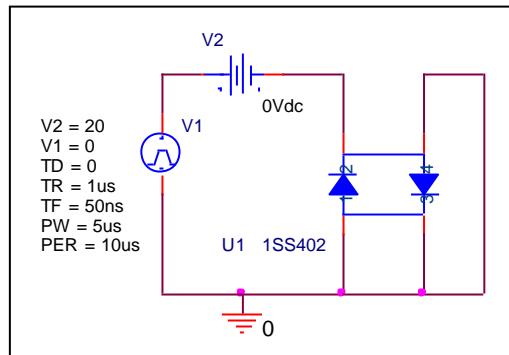
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.000005	0.270	0.269	-0.33
0.00001	0.280	0.287	2.50
0.0001	0.348	0.347	-0.40
0.001	0.405	0.407	0.40
0.002	0.425	0.425	0.00
0.005	0.448	0.450	0.45
0.01	0.468	0.470	0.45
0.05	0.520	0.529	1.79

## Junction Capacitance Characteristic

Circuit Simulation Result

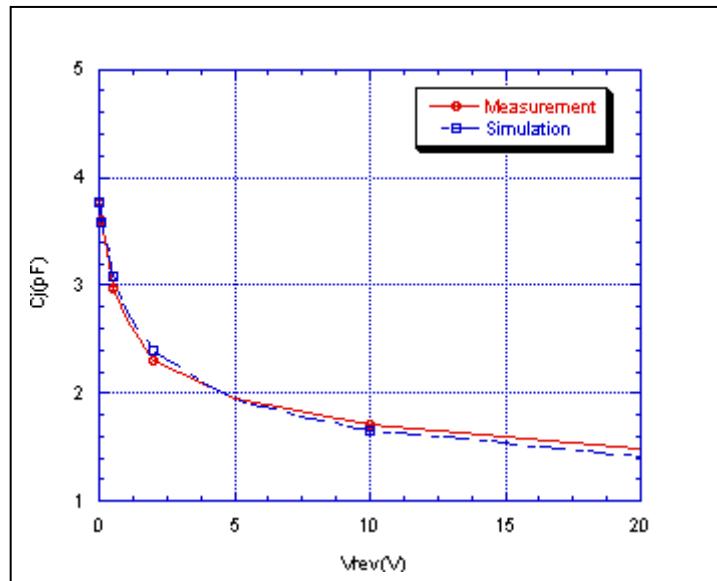


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
0.1	3.600	3.590	-0.28
0.2	3.420	3.419	-0.03
0.5	2.980	3.077	3.26
1	2.680	2.748	2.54
2	2.300	2.390	3.91
5	1.950	1.946	-0.21
10	1.700	1.646	-3.18
20	1.460	1.388	-4.93